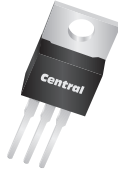


TIP31
TIP31A
TIP31B
TIP31C
SILICON
NPN POWER TRANSISTORS



TO-220 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR TIP31 series devices are silicon NPN epitaxial-base power transistors designed for power amplifier and high speed switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	TIP31	TIP31A	TIP31B	TIP31C	UNITS
Collector-Base Voltage	V_{CBO}	40	60	80	100	V
Collector-Emitter Voltage	V_{CEO}	40	60	80	100	V
Emitter-Base Voltage	V_{EBO}			5.0		V
Continuous Collector Current	I_C			3.0		A
Peak Collector Current	I_{CM}			5.0		A
Continuous Base Current	I_B			1.0		A
Power Dissipation	P_D			40		W
Power Dissipation ($T_A=25^\circ\text{C}$)	P_D			2.0		W
Operating and Storage Junction Temperature	T_J, T_{stg}			-65 to +150		$^\circ\text{C}$
Thermal Resistance	Θ_{JA}			62.5		$^\circ\text{C/W}$
Thermal Resistance	Θ_{JC}			3.13		$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

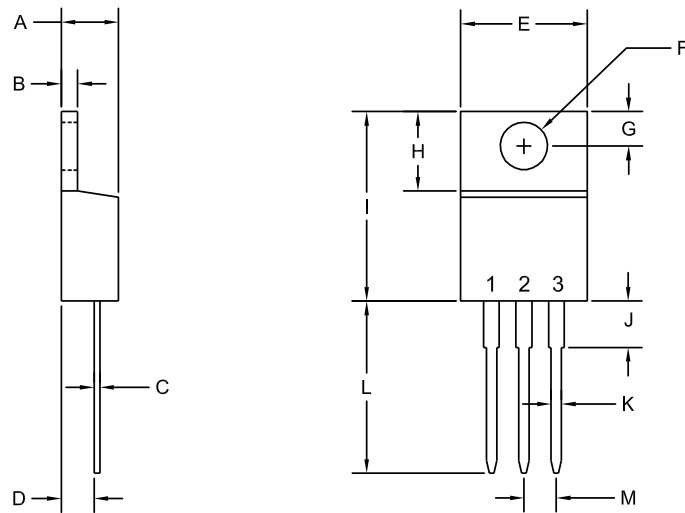
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CEO}	$V_{CE}=30\text{V}$ (TIP31, TIP31A)			0.3	mA
I_{CEO}	$V_{CE}=60\text{V}$ (TIP31B, TIP31C)			0.3	mA
I_{CES}	$V_{CE}=\text{Rated } V_{CEO}$			0.2	mA
I_{EBO}	$V_{EB}=5.0\text{V}$			1.0	mA
BV_{CEO}	$I_C=30\text{mA}$ (TIP31)	40			V
BV_{CEO}	$I_C=30\text{mA}$ (TIP31A)	60			V
BV_{CEO}	$I_C=30\text{mA}$ (TIP31B)	80			V
BV_{CEO}	$I_C=30\text{mA}$ (TIP31C)	100			V
$V_{CE(SAT)}$	$I_C=3.0\text{A}, I_B=375\text{mA}$			1.2	V
$V_{BE(ON)}$	$V_{CE}=4.0\text{V}, I_C=3.0\text{A}$			1.8	V
h_{FE}	$V_{CE}=4.0\text{V}, I_C=1.0\text{A}$	25			
h_{FE}	$V_{CE}=4.0\text{V}, I_C=3.0\text{A}$	10		50	
h_{fe}	$V_{CE}=10\text{V}, I_C=0.5\text{A}, f=1.0\text{kHz}$	20			
f_T	$V_{CE}=10\text{V}, I_C=0.5\text{A}, f=1.0\text{MHz}$	3.0			MHz
t_{on}	$I_C=1.0\text{A}, I_{B1}=I_{B2}=0.1\text{A}, R_L=30\Omega$		0.3		μs
t_{off}	$I_C=1.0\text{A}, I_{B1}=I_{B2}=0.1\text{A}, R_L=30\Omega$		1.0		μs

R0 (12-June 2014)

TIP31
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TO-220 CASE - MECHANICAL OUTLINE



R2

LEAD CODE:

- 1) Base
- 2) Collector
- 3) Emitter
- Tab) Collector

MARKING:

FULL PART NUMBER

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.170	0.190	4.31	4.82
B	0.045	0.055	1.15	1.39
C	0.013	0.026	0.33	0.65
D	0.083	0.107	2.10	2.72
E	0.394	0.417	10.01	10.60
F (DIA)	0.140	0.157	3.55	4.00
G	0.100	0.118	2.54	3.00
H	0.230	0.270	5.85	6.85
I	0.560	0.625	14.23	15.87
J	-	0.250	-	6.35
K	0.025	0.038	0.64	0.96
L	0.500	0.579	12.70	14.70
M	0.090	0.110	2.29	2.79

TO-220 (REV: R2)

R0 (12-June 2014)



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

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